

## LM160/LM360 High Speed Differential Comparator

### General Description

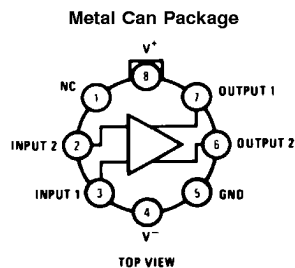
The LM160/LM360 is a very high speed differential input, complementary TTL output voltage comparator with improved characteristics over the  $\mu\text{A}760/\mu\text{A}760\text{C}$ , for which it is a pin-for-pin replacement. The device has been optimized for greater speed, input impedance and fan-out, and lower input offset voltage. Typically delay varies only 3 ns for overdrive variations of 5 mV to 400 mV.

Complementary outputs having minimum skew are provided. Applications involve high speed analog to digital converters and zero-crossing detectors in disk file systems.

### Features

- Guaranteed high speed: 20 ns max
- Tight delay matching on both outputs
- Complementary TTL outputs
- High input impedance
- Low speed variation with overdrive variation
- Fan-out of 4
- Low input offset voltage
- Series 74 TTL compatible

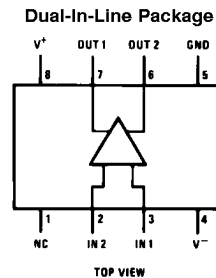
### Connection Diagrams



DS005707-4

Order Number LM160H/883 (Note 1) or LM360H  
See NS Package Number H08C

**Note 1:** Also available in SMD# 5962-8767401



DS005707-5

Order Number LM360M or LM360N  
See NS Package Number M08A or N08E

## Absolute Maximum Ratings (Notes 6, 8)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

|                             |                            |
|-----------------------------|----------------------------|
| Positive Supply Voltage     | +8V                        |
| Negative Supply Voltage     | −8V                        |
| Peak Output Current         | 20 mA                      |
| Differential Input Voltage  | ±5V                        |
| Input Voltage               | $V^+ \geq V_{IN} \geq V^-$ |
| ESD Tolerance (Note 9)      | 1600V                      |
| Operating Temperature Range |                            |
| LM160                       | −55°C to +125°C            |
| LM360                       | 0°C to +70°C               |

|                                                                                                                                     |                 |
|-------------------------------------------------------------------------------------------------------------------------------------|-----------------|
| Storage Temperature Range                                                                                                           | −65°C to +150°C |
| Lead Temperature<br>(Soldering, 10 sec.)                                                                                            | 260°C           |
| Soldering Information                                                                                                               |                 |
| Dual-In-Line Package                                                                                                                |                 |
| Soldering (10 seconds)                                                                                                              | 260°C           |
| Small Outline Package                                                                                                               |                 |
| Vapor Phase (60 seconds)                                                                                                            | 215°C           |
| Infrared (15 seconds)                                                                                                               | 220°C           |
| See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices. |                 |

## Electrical Characteristics

( $T_{MIN} \leq T_A \leq T_{MAX}$ )

| Parameter                                               | Conditions                                                    | Min  | Typ  | Max  | Units |
|---------------------------------------------------------|---------------------------------------------------------------|------|------|------|-------|
| Operating Conditions                                    |                                                               |      |      |      |       |
| Supply Voltage $V_{CC}^+$                               |                                                               | 4.5  | 5    | 6.5  | V     |
| Supply Voltage $V_{CC}^-$                               |                                                               | −4.5 | −5   | −6.5 | V     |
| Input Offset Voltage                                    | $R_S \leq 200\Omega$                                          |      | 2    | 5    | mV    |
| Input Offset Current                                    |                                                               |      | 0.5  | 3    | μA    |
| Input Bias Current                                      |                                                               |      | 5    | 20   | μA    |
| Output Resistance (Either Output)                       | $V_{OUT} = V_{OH}$                                            |      | 100  |      | Ω     |
| Response Time                                           | $T_A = 25^\circ\text{C}$ , $V_S = \pm 5\text{V}$ (Notes 2, 7) |      | 13   | 25   | ns    |
|                                                         | $T_A = 25^\circ\text{C}$ , $V_S = \pm 5\text{V}$ (Notes 3, 7) |      | 12   | 20   | ns    |
|                                                         | $T_A = 25^\circ\text{C}$ , $V_S = \pm 5\text{V}$ (Notes 4, 7) |      | 14   |      | ns    |
| Response Time Difference between Outputs                |                                                               |      |      |      |       |
| ( $t_{pd}$ of $+V_{IN1}$ ) − ( $t_{pd}$ of $-V_{IN2}$ ) | $T_A = 25^\circ\text{C}$ (Notes 2, 7)                         |      | 2    |      | ns    |
| ( $t_{pd}$ of $+V_{IN2}$ ) − ( $t_{pd}$ of $-V_{IN1}$ ) | $T_A = 25^\circ\text{C}$ (Notes 2, 7)                         |      | 2    |      | ns    |
| ( $t_{pd}$ of $+V_{IN1}$ ) − ( $t_{pd}$ of $+V_{IN2}$ ) | $T_A = 25^\circ\text{C}$ (Notes 2, 7)                         |      | 2    |      | ns    |
| ( $t_{pd}$ of $-V_{IN1}$ ) − ( $t_{pd}$ of $-V_{IN2}$ ) | $T_A = 25^\circ\text{C}$ (Notes 2, 7)                         |      | 2    |      | ns    |
| Input Resistance                                        | $f = 1\text{ MHz}$                                            |      | 17   |      | kΩ    |
| Input Capacitance                                       | $f = 1\text{ MHz}$                                            |      | 3    |      | pF    |
| Average Temperature Coefficient of Input Offset Voltage | $R_S = 50\Omega$                                              |      | 8    |      | μV/°C |
| Average Temperature Coefficient of Input Offset Current |                                                               |      | 7    |      | nA/°C |
| Common Mode Input Voltage Range                         | $V_S = \pm 6.5\text{V}$                                       | ±4   | ±4.5 |      | V     |
| Differential Input Voltage Range                        |                                                               | ±5   |      |      | V     |
| Output High Voltage (Either Output)                     | $I_{OUT} = -320\text{ }\mu\text{A}$ , $V_S = \pm 4.5\text{V}$ | 2.4  | 3    |      | V     |
| Output Low Voltage (Either Output)                      | $I_{SINK} = 6.4\text{ mA}$                                    |      | 0.25 | 0.4  | V     |
| Positive Supply Current                                 | $V_S = \pm 6.5\text{V}$                                       |      | 18   | 32   | mA    |
| Negative Supply Current                                 | $V_S = \pm 6.5\text{V}$                                       |      | −9   | −16  | mA    |

**Note 2:** Response time measured from the 50% point of a 30 mVp-p 10 MHz sinusoidal input to the 50% point of the output.

**Note 3:** Response time measured from the 50% point of a 2 Vp-p 10 MHz sinusoidal input to the 50% point of the output.

**Note 4:** Response time measured from the start of a 100 mV input step with 5 mV overdrive to the time when the output crosses the logic threshold.

**Note 5:** Typical thermal impedances are as follows:

|                 |               |         |            |               |         |                       |
|-----------------|---------------|---------|------------|---------------|---------|-----------------------|
| Cavity DIP (J): | $\theta_{JA}$ | 135°C/W | Header (H) | $\theta_{JA}$ | 165°C/W | (Still Air)           |
| Molded DIP (N): | $\theta_{JA}$ | 130°C/W |            |               | 67°C/W  | (400 LF/min Air Flow) |
|                 |               |         |            | $\theta_{JC}$ | 25°C/W  |                       |

**Note 6:** The device may be damaged if used beyond the maximum ratings.

**Note 7:** Measurements are made in AC Test Circuit, Fanout = 1

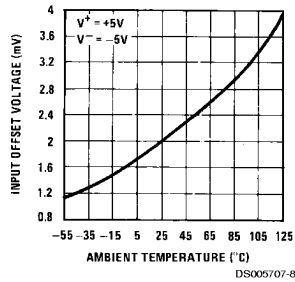
**Note 8:** Refer to RETS 160X for LM160H, LM160J-14 and LM160J military specifications.

## Electrical Characteristics (Continued)

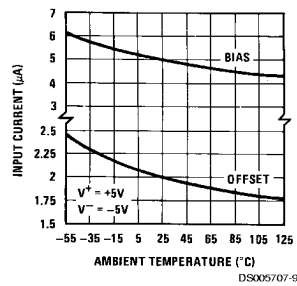
Note 9: Human body model, 1.5 k $\Omega$  in series with 100 pF.

### Typical Performance Characteristics

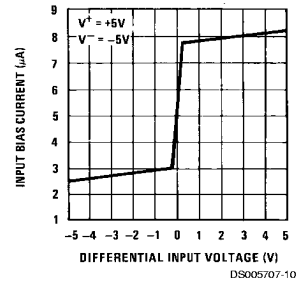
Offset Voltage



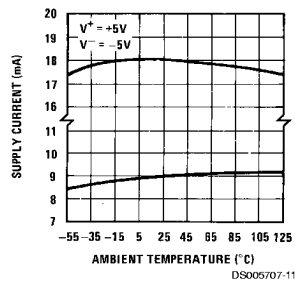
Input Current vs Ambient Temperature



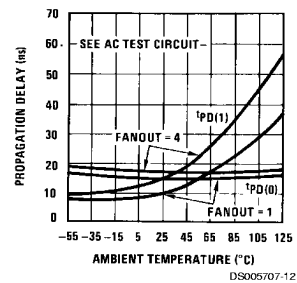
Input Characteristics



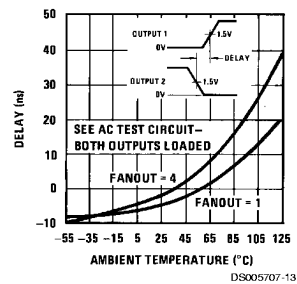
Supply Current vs Ambient Temperature



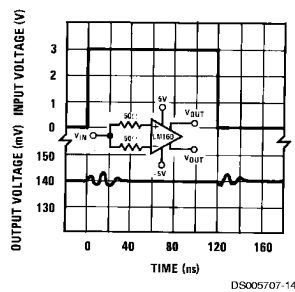
Propagation Delay vs Ambient Temperature



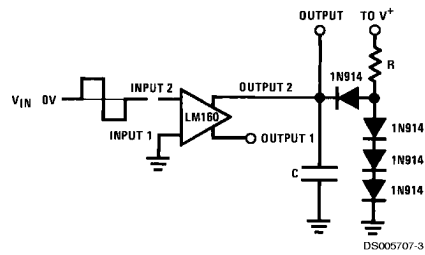
Delay of Output 1 With Respect to Output 2 vs Ambient Temperature



Common-Mode Pulse Response

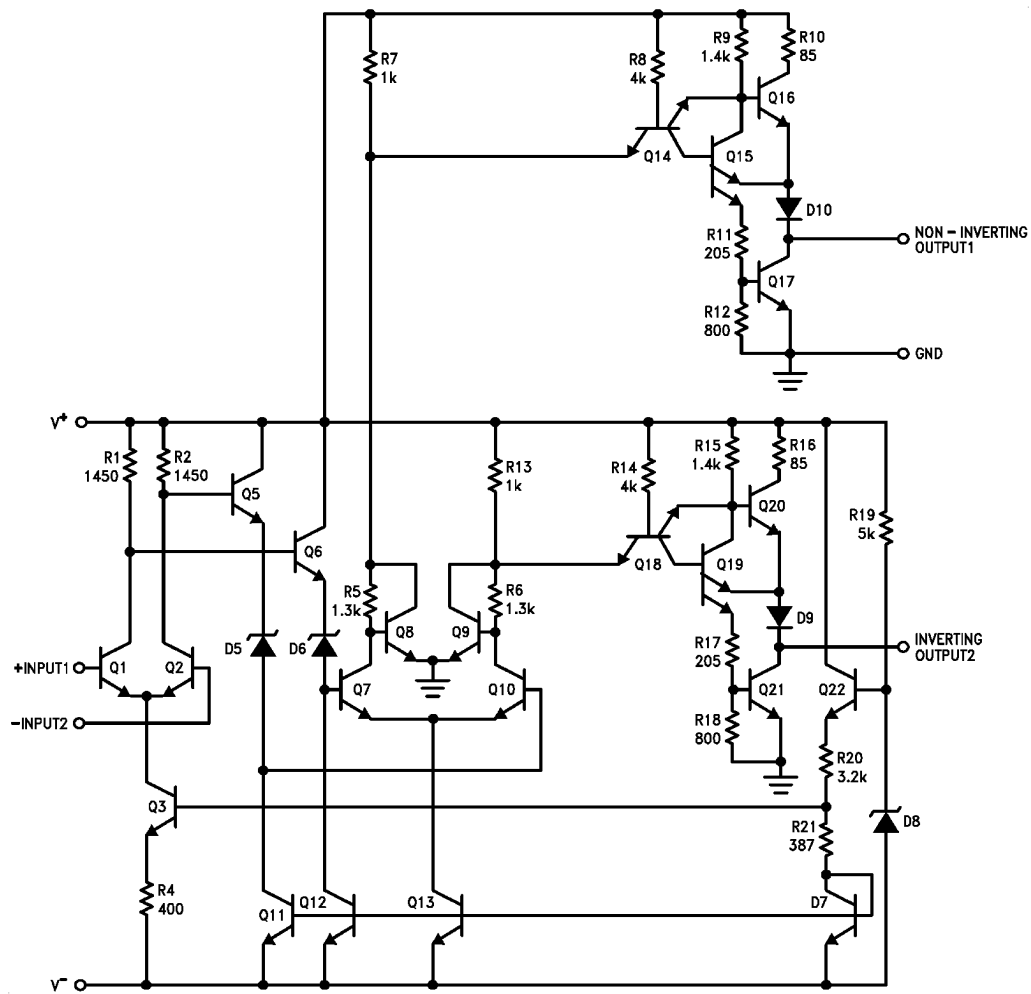


## AC Test Circuit

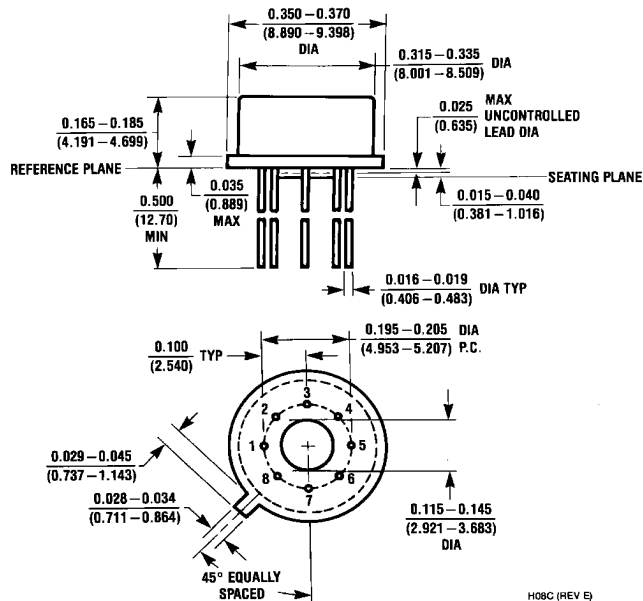


$V_{IN} = \pm 50 \text{ mV}$     FANOUT=1    FANOUT=4  
 $V^+ = +5V$      $R = 2.4k$      $R = 630\Omega$   
 $V^- = -5V$      $C = 15 \text{ pF}$      $C = 30 \text{ pF}$

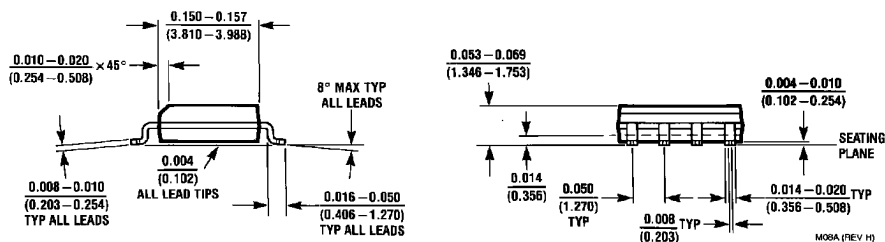
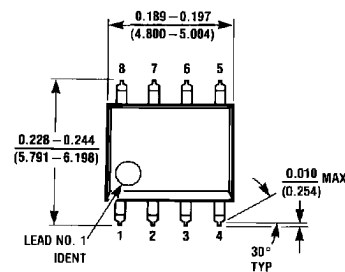
# Schematic Diagram



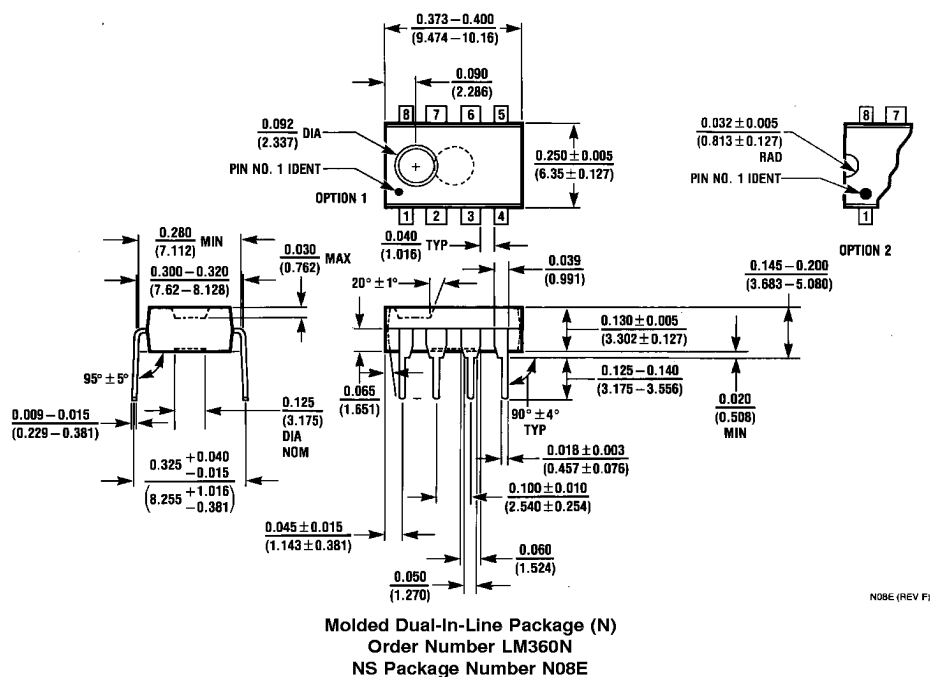
D5005707-1

**Physical Dimensions** inches (millimeters) unless otherwise noted

**Metal Can Package (H)**  
**Order Number LM160H/883 or LM360H**  
**NS Package Number H08C**



**Molded Dual-In-Line Package (M)**  
**Order Number LM360M**  
**NS Package Number M08A**

**Physical Dimensions** inches (millimeters) unless otherwise noted (Continued)**LIFE SUPPORT POLICY**

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**National Semiconductor Corporation**  
Americas  
Tel: 1-800-272-9959  
Fax: 1-800-737-7018  
Email: support@nsc.com

www.national.com

**National Semiconductor Europe**

Fax: +49 (0) 1 80-530 85 86  
Email: europe.support@nsc.com  
Deutsch Tel: +49 (0) 1 80-530 85 85  
English Tel: +49 (0) 1 80-532 78 32  
Français Tel: +49 (0) 1 80-532 93 58  
Italiano Tel: +49 (0) 1 80-534 16 80

**National Semiconductor Asia Pacific Customer Response Group**

Tel: 65-2544466  
Fax: 65-2504466  
Email: sea.support@nsc.com

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